



HIGH SPEED CMOS TIMER

GENERAL DESCRIPTION

The ALD555 timer is a high performance monolithic timing circuit built with advanced silicon gate CMOS technology. It offers the benefits of high input impedance, thereby allowing smaller timing capacitors and longer timing cycle; high speed, with typical cycle time of 500ns; low power dissipation for battery operated environment; reduced supply current spikes, allowing smaller and lower cost decoupling capacitors. It is capable of producing accurate time delays and oscillations in both monostable and astable operation. It operates in the one-shot (monostable) mode or 50% duty cycle free running oscillation mode with a single resistor and one capacitor. The inputs and outputs are fully compatible with CMOS, NMOS or TTL logic.

There are three matched internal resistors (approximately 200K Ω each) that set the threshold and trigger levels at two-thirds and one-third respectively of V⁺. These levels can be adjusted by using the control terminal (pin 5). When the trigger input is below the trigger level, the output is in the high state and sourcing 2mA. When threshold input is above the threshold level at the same time the trigger input is above the trigger level, the internal flip-flop is reset, the output goes to the low state and sinks up to 10mA. The reset input overrides all other inputs and when it is active (reset voltage less than 1V), the output is in the low state.

FEATURES

- Functional equivalent to NE555 with greatly expanded high and low frequency ranges
- High speed, low power, monolithic CMOS technology
- Low supply current: 100 μ A typical
- Extremely low trigger, threshold and reset currents: 1pA typical
- High speed operation -- 2MHz oscillation
- Low operating supply voltage of 2 to 12V
- Operates in both monostable and astable modes
- Fixed 50% duty cycle or adjustable duty cycle
- CMOS, NMOS and TTL compatible input/output
- High discharge sinking current of 80mA
- Low supply current spikes

ORDERING INFORMATION ("L" suffix denotes lead-free (RoHS))

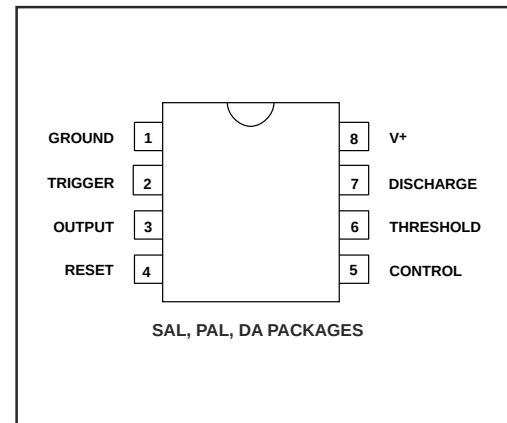
Operating Temperature Range *		
0°C to +70°C	0°C to +70°C	-55°C to +125°C
8-Pin Small Outline Package (SOIC)	8-Pin Plastic DIP Package	8-Pin CERDIP Package
ALD555SAL	ALD555PAL	ALD555DA

* Contact factory for leaded (non-RoHS) or high temperature versions.

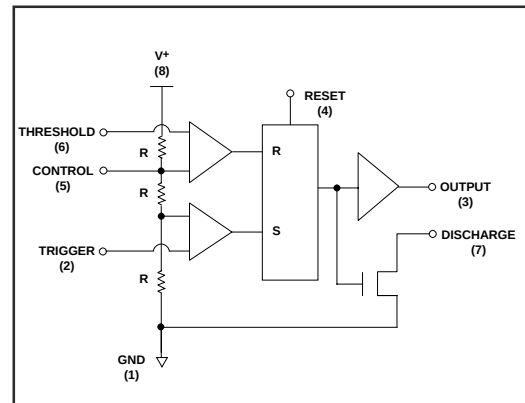
APPLICATIONS

- High speed one-shot (monostable) pulse generation
- Precision timing
- Sequential timing
- Long delay timer
- Pulse width and pulse position modulation
- Missing pulse detector
- Frequency divider

PIN CONFIGURATION



BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Supply voltage, V^+ _____ 13.2V
 Input voltage range _____ -0.3V to V^+ +0.3V
 Power dissipation _____ 600 mW
 Operating temperature range SAL, PAL packages _____ 0°C to + 70°C
 DA package _____ -55°C to +125°C
 Storage temperature range _____ -65°C to +150°C
 Lead temperature, 10 seconds _____ +260°C

OPERATING ELECTRICAL CHARACTERISTICS

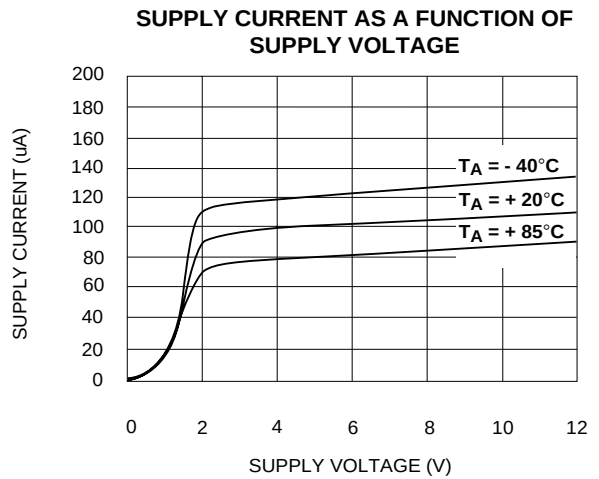
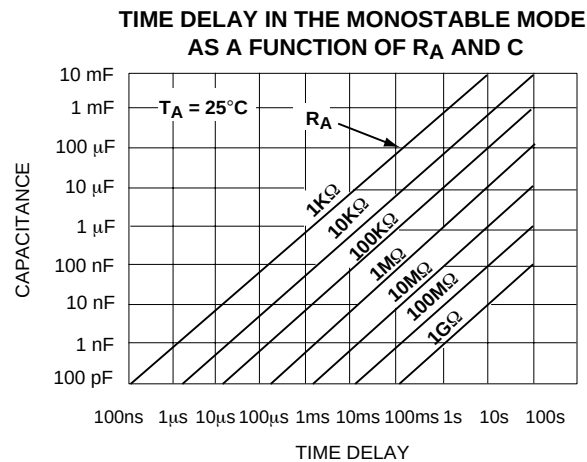
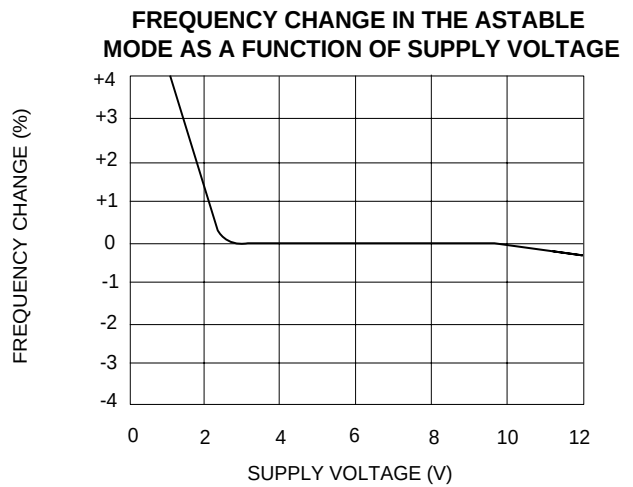
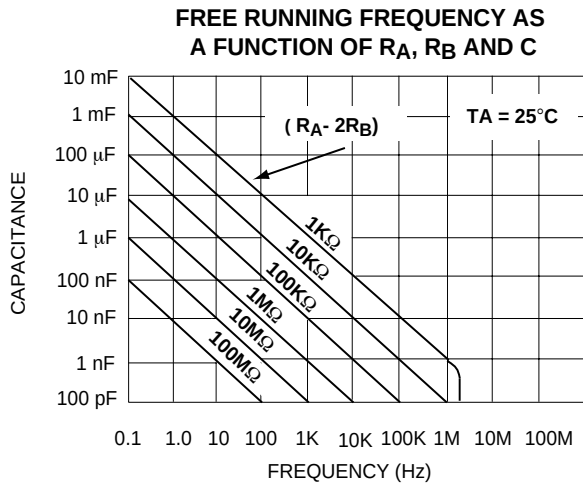
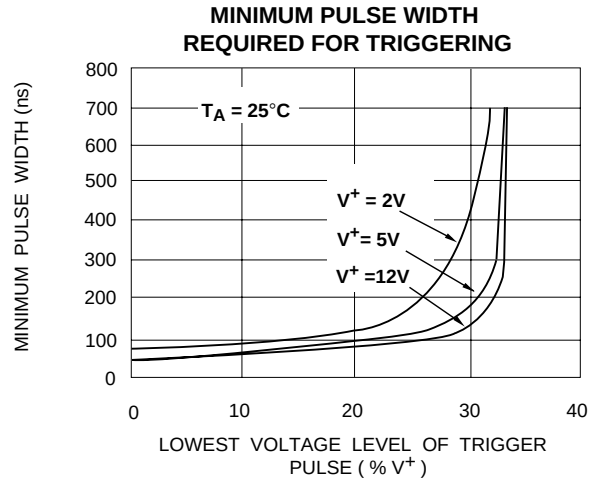
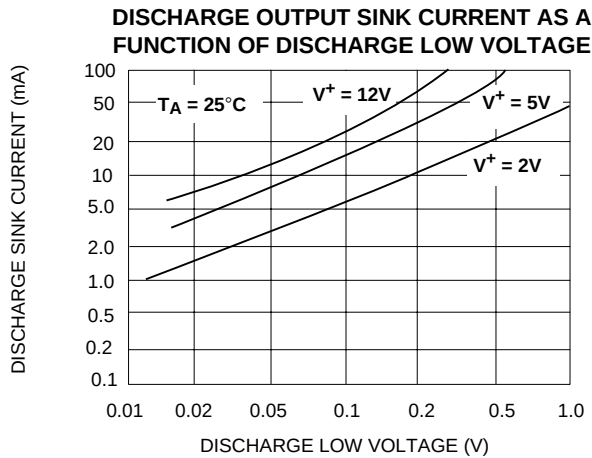
$T_A = 25^\circ\text{C}$ $V^+ = +5\text{V}$ unless otherwise specified

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
Supply Voltage	V^+	2		12	V	
Supply Current	I_S		100	180	μA	Outputs Unloaded
Timing error / Astable mode Initial Accuracy	t_{err}		1.0	2.2	%	$C = 0.1\mu\text{F}$ $R_A = 1\text{K}\Omega$ $R_B = 1\text{K}\Omega$
Drift with Temperature ¹ Drift with Supply Voltage ¹	$\Delta t/\Delta T$ $\Delta t/\Delta V^+$		10.0 0.1		ppm/ $^\circ\text{C}$ %/V	
Threshold Voltage	V_{TH}	3.233	3.333	3.433	V	
Trigger Voltage	V_{TRIG}	1.607	1.667	1.737	V	
Trigger Current ²	I_{TRIG}		.001	0.2	nA	
Reset Voltage	V_{RST}	0.4	0.7	1.0	V	
Reset Current ²	I_{RST}		.001	0.2	nA	
Threshold Current ²	I_{TH}		.001	0.2	nA	
Control Voltage Level	V_{CONT}	3.273	3.333	3.393	V	
Output Voltage Drop (Low)	V_{OL}		0.2	0.4	V	$I_{SINK} = 10\text{mA}$
Output Voltage Drop (High)	V_{OH}			4.2	V	$I_{SOURCE} = -2\text{mA}$
Rise Time of Output ¹	t_r		15	30	ns	$R_L = 10\text{M}\Omega$ $C_L = 10\text{pF}$
Fall Time of Output ¹	t_f		10	30	ns	
Discharge Transistor Leakage Current	I_{DL}		.01		nA	
Discharge Voltage Drop	V_{DISC}		0.5 0.2	1.0 0.4	V V	$I_{DISCHARGE} = 80\text{mA}$ $I_{DISCHARGE} = 30\text{mA}$
Maximum Frequency Astable Mode	f_{MAX}	1.4	2		MHz	$R_A = 470\Omega$ $R_B = 200\Omega$ $C_T = 200\text{pF}$

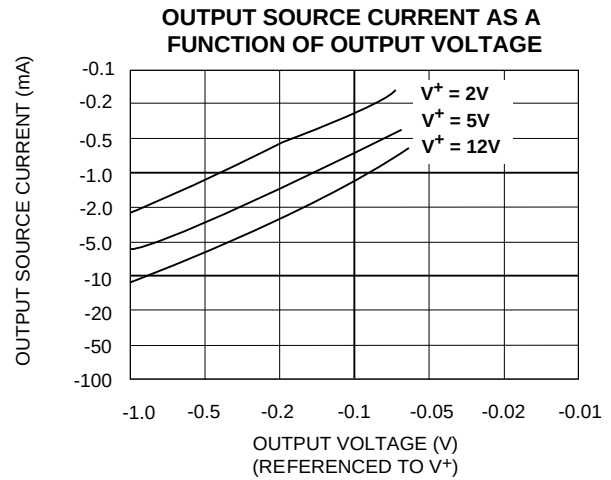
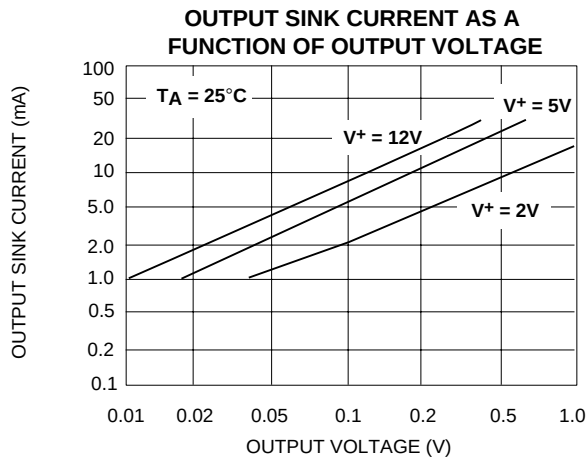
Notes: ¹ Sample tested parameters.

² Consists of junction leakage currents with strong temperature dependence.

TYPICAL PERFORMANCE CHARACTERISTICS

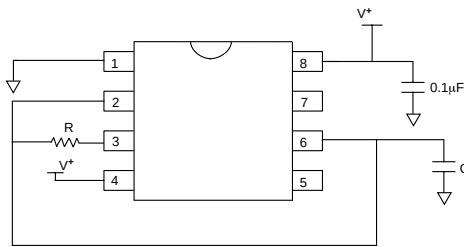


TYPICAL PERFORMANCE CHARACTERISTICS (cont'd)



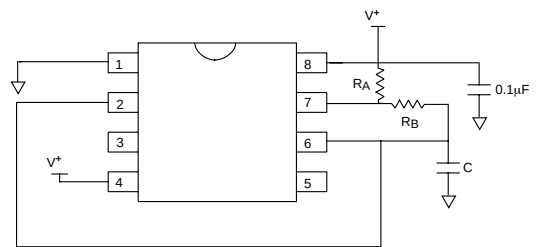
TYPICAL APPLICATIONS

ASTABLE MODE OPERATION 50% DUTY CYCLE



$$\text{Frequency } f = 1 / (1.4 R_C)$$

ASTABLE MODE OPERATION (FREE RUNNING OSCILLATOR)

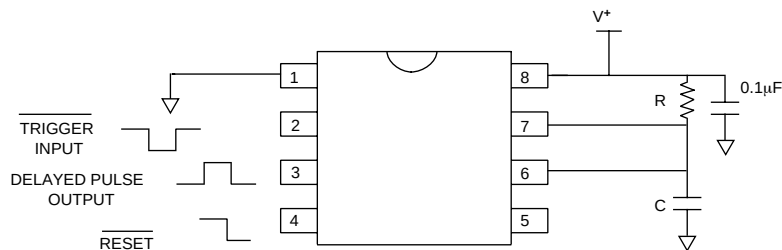


$$\text{Frequency } f = 1.46 / (R_A + 2R_B)C$$

$$\text{Duty Cycle DC} = R_B / (R_A + 2R_B)$$

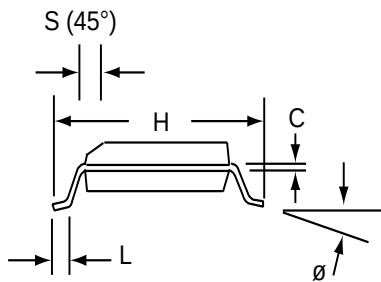
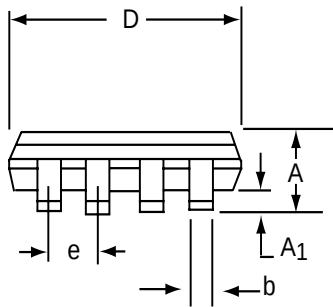
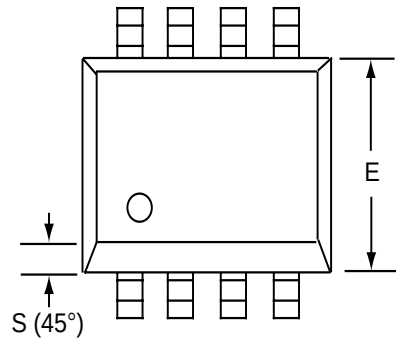
MONOSTABLE MODE OPERATION (ONE SHOT PULSE)

Pulse Delay $t_d = 1.1 R_C$



SOIC-8 PACKAGE DRAWING

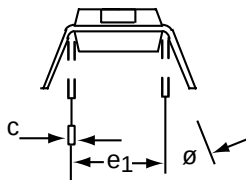
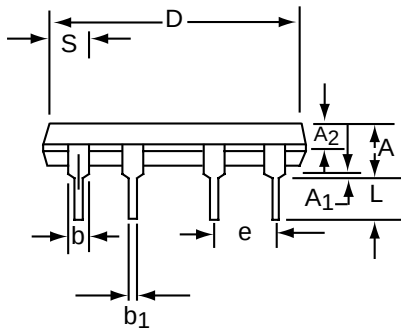
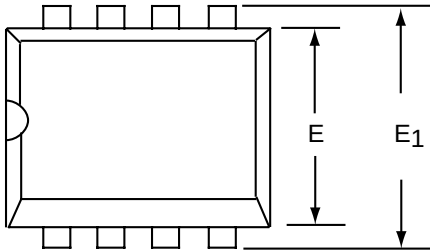
8 Pin Plastic SOIC Package



Dim	Millimeters		Inches	
	Min	Max	Min	Max
A	1.35	1.75	0.053	0.069
A ₁	0.10	0.25	0.004	0.010
b	0.35	0.45	0.014	0.018
C	0.18	0.25	0.007	0.010
D-8	4.69	5.00	0.185	0.196
E	3.50	4.05	0.140	0.160
e	1.27 BSC		0.050 BSC	
H	5.70	6.30	0.224	0.248
L	0.60	0.937	0.024	0.037
Ø	0°	8°	0°	8°
S	0.25	0.50	0.010	0.020

PDIP-8 PACKAGE DRAWING

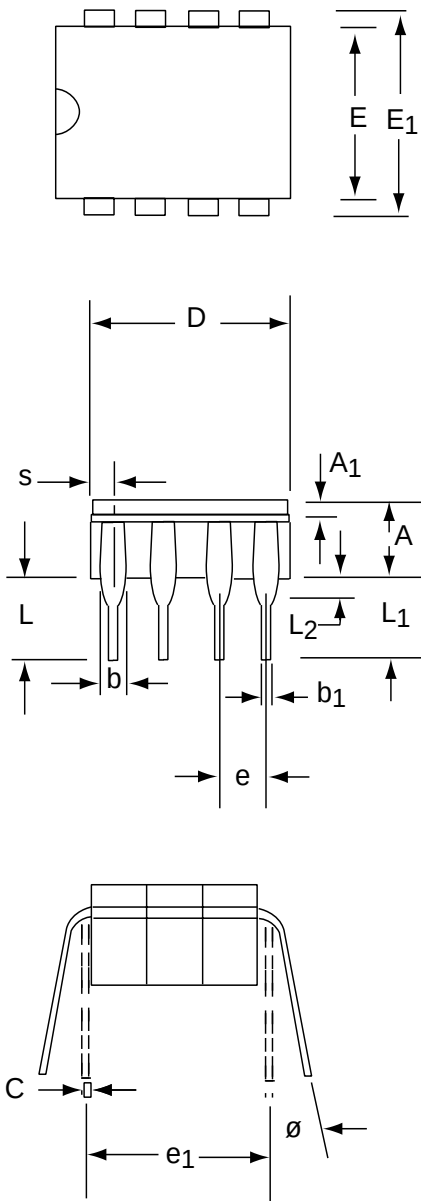
8 Pin Plastic DIP Package



Dim	Millimeters		Inches	
	Min	Max	Min	Max
A	3.81	5.08	0.105	0.200
A ₁	0.38	1.27	0.015	0.050
A ₂	1.27	2.03	0.050	0.080
b	0.89	1.65	0.035	0.065
b ₁	0.38	0.51	0.015	0.020
c	0.20	0.30	0.008	0.012
D-8	9.40	11.68	0.370	0.460
E	5.59	7.11	0.220	0.280
E ₁	7.62	8.26	0.300	0.325
e	2.29	2.79	0.090	0.110
e ₁	7.37	7.87	0.290	0.310
L	2.79	3.81	0.110	0.150
S-8	1.02	2.03	0.040	0.080
Ø	0°	15°	0°	15°

CERDIP-8 PACKAGE DRAWING

8 Pin CERDIP Package



Dim	Millimeters		Inches	
	Min	Max	Min	Max
A	3.55	5.08	0.140	0.200
A ₁	1.27	2.16	0.050	0.085
b	0.97	1.65	0.038	0.065
b ₁	0.36	0.58	0.014	0.023
C	0.20	0.38	0.008	0.015
D-8	--	10.29	--	0.405
E	5.59	7.87	0.220	0.310
E ₁	7.73	8.26	0.290	0.325
e	2.54 BSC		0.100 BSC	
e ₁	7.62 BSC		0.300 BSC	
L	3.81	5.08	0.150	0.200
L ₁	3.18	--	0.125	--
L ₂	0.38	1.78	0.015	0.070
S	--	2.49	--	0.098
Ø	0°	15°	0°	15°